

Vishay Siliconix

Dual N-Channel 2.5-V (G-S) Input Protected Load Switch

PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)		
	0.030 at V_{GS} = 4.5 V	4.5			
20	0.033 at V _{GS} = 3.0 V	4.2	7.6		
	0.035 at V _{GS} = 2.5 V	3.9			

FEATURES

- Halogen-free
- Low R_{DS(on)}
- V_{GS} Max Rating: 14 V





DESCRIPTION

The Si6926AEDQ is a dual N-Channel MOSFET with ESD protection and gate over-voltage protection circuitry incorporated into the MOSFET. The device is designed for use in Lithium Ion battery pack circuits. The 2-stage input protection circuit is a unique design, consisting of two stages of back-to-back zener diodes separated by a resistor. The first stage diode is designed to absorb most of the ESD energy. The second stage diode is designed to protect the gate from any remaining ESD energy and over-voltages

above the gates inherent safe operating range. The series resistor used to limit the current through the second stage diode during over voltage conditions has a maximum value which limits the input current to \leq 10 mA at 14 V and the maximum t_{off} to 15 μs . The Si6926AEDQ has been optimized as a battery or load switch in Lithium Ion applications with the advantage of both a 2.5 V R_{DS(on)} rating and a safe 14 V gate-to-source maximum rating.

APPLICATION CIRCUITS

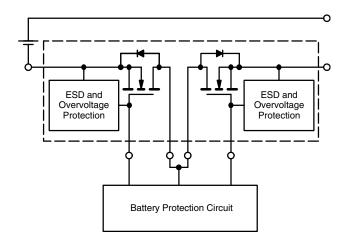
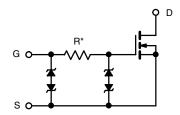


Figure 1. Typical Use In a Lithium Ion Battery Pack



*R typical value is 1.9 k Ω by design.

See Typical Characteristics, Gate-Current vs. Gate-Source Voltage, Page 3.

Figure 2. Input ESD and Overvoltage Protection Circuit

Si6926AEDQ

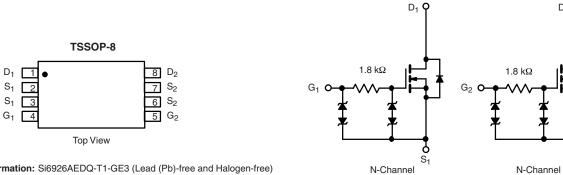
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FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Ordering Information: Si6926AEDQ-T1-GE3 (Lead (Pb)-free and Halogen-free)

Figure 3.

Figure 4.

ABSOLUTE MAXIMUM RATINGS T_A	= 25 °C, unle	ss otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage, Source-Drain Voltage		V _{DS}	20		V	
Gate-Source Voltage		V _{GS}	± 14			
	T _A = 25 °C	- I _D	4.5	4.1	٨	
Continuous Drain-to-Source Current $(T_J = 150 \ ^\circ C)^a$	T _A = 70 °C		3.6	3.3		
Pulsed Drain-to-Source Current		I _{DM}	20		A	
Pulsed Source Current (Diode Conduction) ^a		۱ _S	0.83	0.69		
	T _A = 25 °C	- P _D	1.0	0.83	W	
Maximum Power Dissipation ^a	T _A = 70 °C		0.64	0.53	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	R _{thJA}	90	125	
Maximum Junction-to-Ambient ^a	Steady State		126	150	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	65	80	

Notes:

a. Surface Mounted on FR4 board.



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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				•	•		
Gate Threshold Voltage V _{GS(t}		$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.4		1.2	V	
Cata Dady Laskage	I _{GSS} -	$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$			± 1	μA	
Gate-Body Leakage		$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 10	mA	
	I _{DSS}	$V_{DS} = 20 V, V_{GS} = 0 V$			1		
Zero Gate Voltage Drain Current		V_{DS} = 20 V, V_{GS} = 0 V, T_{J} = 55 °C			5	μΑ	
On-State Drain Current ^b	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 5 \text{ V}$	10			А	
Drain-Source On-State Resistance ^b	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$		0.023	0.030	Ω	
		$V_{GS} = 3.0 \text{ V}, \text{ I}_{D} = 4.2 \text{ A}$		0.025	0.033		
		$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 3.9 \text{ A}$		0.027	0.035		
Forward Transconductance ^b	9 _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$		26		S	
Diode Forward Voltage ^b	V _{SD}	$I_{\rm S} = 0.83$ A, $V_{\rm GS} = 0$ V		0.65	1.1	V	
Dynamic ^a	- -		•	•			
Total Gate Charge	Qg			7.6	12		
Gate-Source Charge	Q _{gs}	V_{DS} = 10 V, V_{GS} = 4.5 V, I_D = 4.5 A		1.5		nC	
Gate-Drain Charge	Q _{gd}			1.5			
Turn-On Delay Time	t _{d(on)}			0.43	0.7		
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		0.8	1.2		
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong \text{1}$ A, V_GEN = 4.5 V, R_g = 6 Ω		5.0	7.5	μs	
Fall Time	t _f			2.5	4.0		

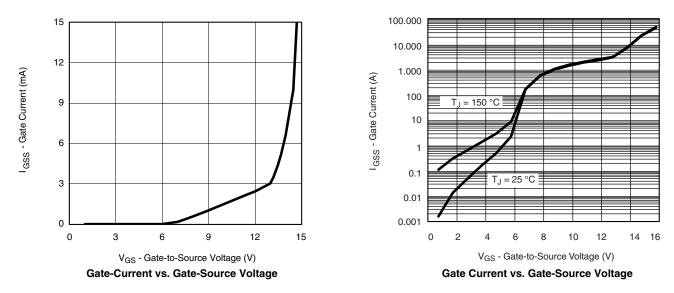
Notes:

a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

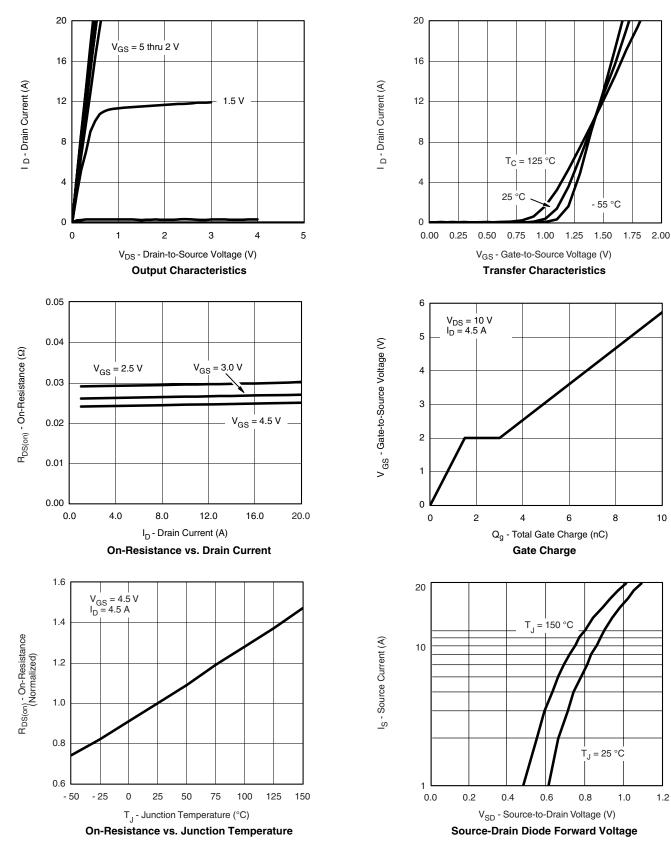


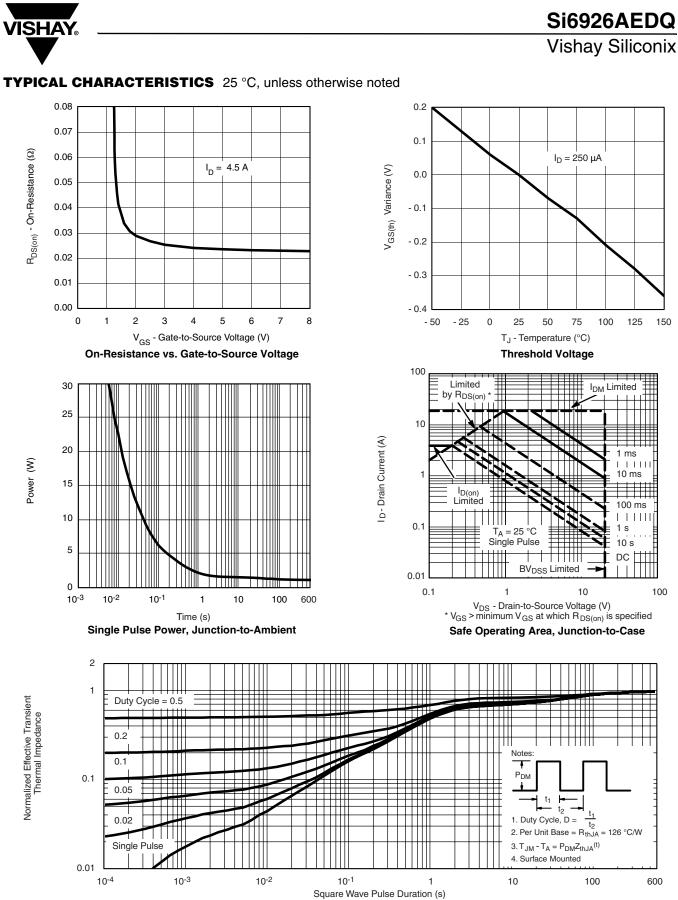
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Normalized Thermal Transient Impedance, Junction-to-Ambient

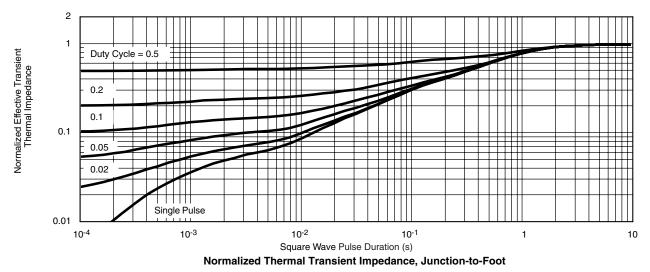
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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